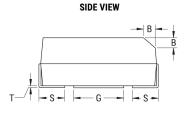


## T500X107K016BG6110

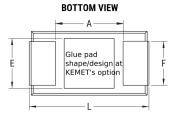
T500, Tantalum, MnO2 Tantalum, High Temperature, 100 uF, 10%, 16 VDC, SMD, MnO2, Molded, High Temperature, 200C, B (0.1%/1000 Hrs), 250 mOhms, 7343, 4.3mm

## CATHODE (-) END VIEW



## ANODE (+) END VIEW





Click here for the 3D model.

Dimensions	,
Footprint	7343
L	7.3mm +/-0.3mm
W	4.3mm +/-0.3mm
Н	4mm +/-0.3mm
Т	0.13mm REF
S	1.3mm +/-0.3mm
F	2.4mm +/-0.1mm
Α	3.8mm MIN
В	0.5mm +/-0.15mm
E	3.5mm REF
G	3.5mm REF
Р	1.7mm REF
R	1mm REF
Χ	0.1mm +/-0.1mm REF

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	500

General Information		
Series	T500	
Dielectric	MnO2 Tantalum	
Style	SMD Chip	
Description	SMD, MnO2, Molded, High Temperature, 200C	
Features	200C	
RoHS	Yes	
Termination	Gold	
AEC-Q200	No	
Shelf Life	156 Weeks	
MSL	1	

Specifications	,
Capacitance	100 uF
Capacitance Tolerance	10%
Voltage DC	16 VDC (85C), 10.6 VDC (125C), 6.4 VDC (200C)
Temperature Range	-55/+200°C
Rated Temperature	85°C
Humidity	85C, 85% RH, 0 V, 1000 Hours
Dissipation Factor	8% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	250 mOhms (100kHz 25C)
Ripple Current	812 mA (rms, 100kHz 25C), 325 mA (rms, 100kHz 125C), 81 mA (rms, 100kHz 200C)
Leakage Current	16 uA (5min 25°C)

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.